Characterization of atomically thin graphene/h-BN stacked heterostructures

Elmahdi Amar^{1, 2}

Tiago Pereira¹, Nicoleta Nicoara¹, Siva N. Sankar¹, Sivajee Kapu¹, Pedro Alpuim¹, Carlos J. Tavares^{1, 2}, and Sascha Sadewasser¹

¹ INL- International Iberian Nanotechnology Laboratory, 4715-330 Braga, Portugal

² Centre of Physics of Minho and Porto Universities (CF-UM-UP), University of Minho, 4710-057 Braga, Portugal

elmahdi.amar@inl.int

Hexagonal boron nitride (h-BN) is a 2D layered material. It contains boron and nitrogen arranged in a sp² hexagonal lattice via covalent bonding [1]. h-BN has attracted wide interest due to its great compatibility with the graphene crystalline structure (Gr). It can be considered as an ideal substrate or an encapsulating layer in graphene-based electronic devices [2]. In this work, graphene and h-BN are grown on a similar Cu foil, but in two separate chemical vapor deposition furnaces to ensure high-quality synthesis of each 2D material. Subsequently, few-layers (1 cm²) of graphene are successfully transferred onto h-BN thin films on SiO₂/Si using a PVA lamination transfer. Raman spectroscopy confirms high-quality graphene domains deposited on h-BN thin films. Graphene number of layer analysis is investigated based on the shape, intensity, and positions of the Raman G and 2D peaks. X-ray photoelectron spectroscopy spectra of graphene/h-BN heterostructures on SiO₂/Si substrates provide insights on the chemical composition and bonding states of the materials involved. Kelvin probe force microscopy (KPFM) reveal variations in the work function between the Gr/h-BN/SiO₂ h-BN/SiO₂ regions (Fig.1). and These differences are attributed to variations in h-BN layer and/or graphene layer thickness, or

due to strain induced by graphene domains formed on fractured h-BN. This work paves the way to synthesize good-quality graphene/h-BN heterostructures on insulating substrates and contributes to nextgeneration graphene-based device applications.



Figure 1: Kelvin probe force microscopy image of monolayer and bilayer graphene on a folded h-BN thin film.

References

- S. K. Jang et al, Sci. Rep., (2016), 6, 30449.
- [2] A. N. Toksumakov et al, Commun. Phys., (2023), 6, 13.

QUANTUMatter2025